

C1206C823G3GACTU

Specifications

Insulation Resistance

Aliases (C1206C823G3GAC7800) SMD Comm COG, Ceramic, 0.082 uF, 2%, 25 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1206, 1.5 mm



General Information	
Series	SMD Comm COG
Style	SMD Chip
Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I
Features	Ultra-Stable, Low Loss, Class I
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	36 mg
Shelf Life	78 Weeks
MSL	1

Dimensions	
Chip Size	1206
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Т	1.6mm +/-0.20mm
S	1.5mm MIN
В	0.5mm +/-0.25mm

Capacitance	0.082 uF
Measurement Condition	1 kHz 1.0Vrms
Tolerance	2%
Voltage DC	25 VDC
Dielectric Withstanding Voltage	62.5 VDC
Temperature Range	-55/+125°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1kHz 1.0Vrms
Dissipation Factor	0.1% 1 kHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour

12.1951 GOhms

Packaging Specifications	
Packaging	T&R, 180mm, Plastic Tape
Packaging Quantity	2000

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